

製品規格承認願  
**Qualification of Products Approval**

To : (주)피에스티

製品名 Product	Bluetooth Antenna
型名 Type	ALA 931C5
申請日 Date	2007. 03. 16



SEJONG TRONICS CO., LTD


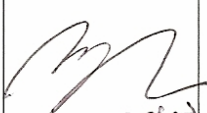


Rm. 1216 Korea-Business 1338-21 Seocho-dong, Seocho-gu, SEOUL, KOREA  
TEL : 82)2-586-6012 FAX : 82)2-586-6082

# APPROVAL SHEET

**Type : Multilayer Chip Antenna**  
**Part No. : ALA931C5**

	Check	Consent	Approval



	Written	Checked		Approved
Amotech	 조영호	 이준호	 김희	 김희
	12/18	12/18	12/18	12/18

2007. 3. 16

**AMOTECH Co., Ltd.**

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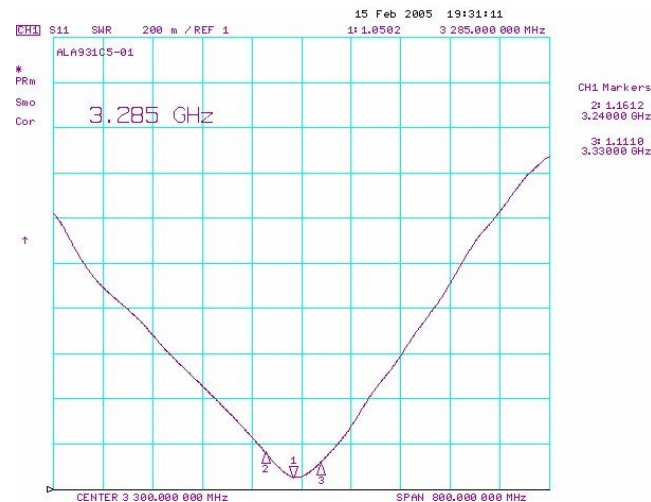
## 1. Revision Record

Date	Title	Content	Remark
2006.12.18		New drawing up	

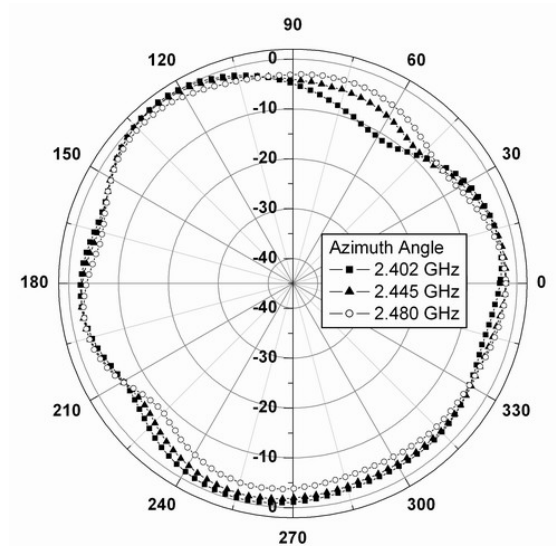
## 2. Specifications

### 2.1 Electrical specifications

No	Item	Spec.	Remark
1	Frequency Range	2400~2500	ISM Band
2	VSWR	Max. 3.0:1 @3285±45 MHz	On manual jig
3	Radiation Gain	Max. 0 dBi @azimuth co-pol.	Measured after matching on testboard
4	Radiation Pattern	Omni-directional	
5	Impedance	Nominal 50 $\Omega$	



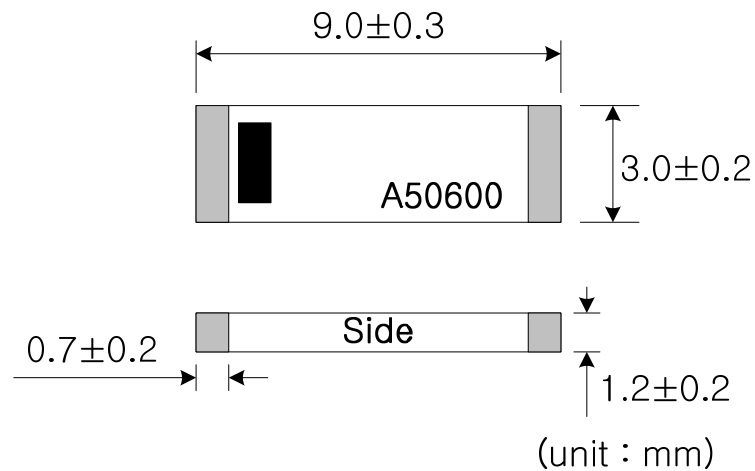
[VSWR : measured on manual jig]



[Radiation Gain : Measured on Ref. Board]

## 2.2 Mechanical specifications

No	Item	Spec.		Unit
1	Dimensions	W	$9.0 \pm 0.3$	mm
		D	$3.0 \pm 0.2$	
		H	$1.2 \pm 0.2$	
2	Unit Weight	$97 \pm 9$		mg
3	Operation Temp.	$-30 \sim +70$		°C
4	Storage Temp.	$-40 \sim +85$		°C



[Chip Antenna dimension]

## 2.3 Index method of Part No. & Lot No.

Part No.	<u>ALA</u> (1)	931 (2)	<u>C5</u> (3)
(1) : Amotech Antenna			
(2) : Chip size			
(3) : Version & frequency			

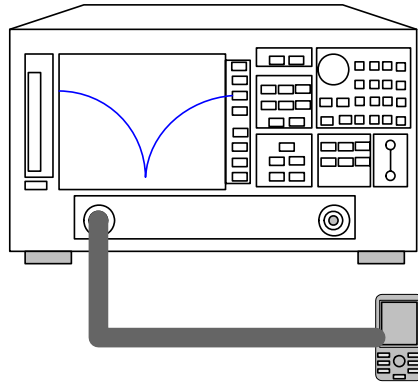
  

Lot No.	<u>MA</u> (1)	<u>09</u> (2)	<u>A5</u> (3)	<u>0506</u> (4)	<u>01</u> (5)
(1) : Mass product Antenna					
(2) : Chip size					
(3) : Version & frequency					
(4) : Y/M					
(5) : Serial No. of product					

### 3. Test Method

#### 3.1 VSWR

Equipment : Network Analyzer 8753ES

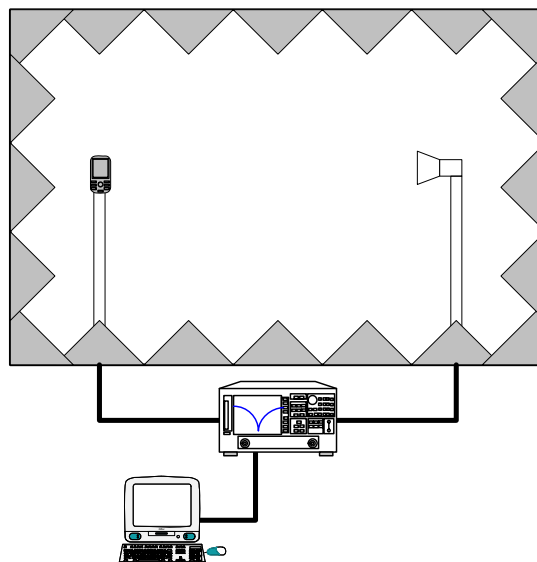


[Test procedure]

- ① Setup as shown picture.
- ② Calibrate Network Analyzer in frequency range of  $f_0 \pm 400$  MHz, verify that the value of return loss( $S_{11}$ ) is under  $-55\text{dB}$  with termination( $50\Omega$ )
- ③ After connect a mobile set or manual jig for single chip antenna to Network Analyzer, measure the max. value of VSWR in frequency range of spec.

#### 3.2 Radiation gain

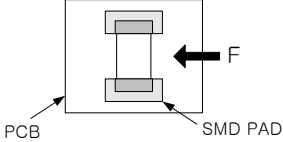
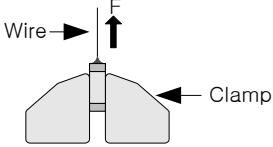
Equipment : Anechoic chamber , Network Analyzer 8753ES



[Test procedure]

- ① Calibrate network analyzer and anechoic chamber using reference horn antenna.
- ② Set-up operation software (frequency, angle step, etc.)
- ③ After connecting AUT on holder, measure radiation gain.

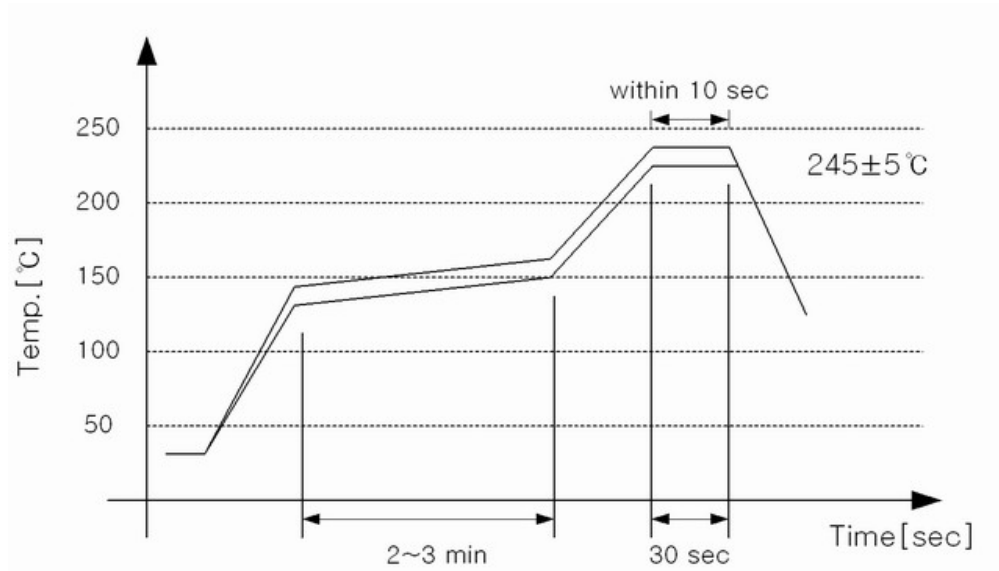
#### 4. Reliability Test

No	ITEM	TEST CONDITION	TEST REQUIREMENTS
1	Adhesive Strength of Termination	<p>1. Applied force on SMD chip till detached point from PCB.</p> 	<p>1. No mechanical damage by forces applied on the right. 2. Strength (F) &gt; 7 kgf</p>
2	Tensile Strength	<p>1. Wire : 0.6~0.8 tined Cu wire</p> 	<p>1. No mechanical damage by forces applied on the right. 2. Strength (F) &gt; 3 kgf</p>
3	Thermal Shock (Temperature Cycle)	<p>1. 1 cycle / step 1 : <math>-40 \pm 3^{\circ}\text{C}</math>, 30 min step 2 : <math>+125 \pm 3^{\circ}\text{C}</math>, 30 min 2. Number of cycle : 30 3. Measure after left for 48 hrs min. at room temperature</p>	<p>1. No visual damage 2. Within electric spec (VSWR)</p>
4	High Temperature Resistance	<p>1. Temperature : <math>+125 \pm 5^{\circ}\text{C}</math> 2. Time : <math>1000 \pm 24</math> hrs 3. Measure <math>f_c</math> after left for 24 hrs min. at room temperature</p>	<p>1. No visual damage 2. Within electric spec (VSWR)</p>
5	Low Temperature Resistance	<p>1. Temperature : <math>-40 \pm 5^{\circ}\text{C}</math> 2. Time : <math>1000 \pm 24</math> hrs 3. Measure <math>f_c</math> after left for 48 hrs min. at room temperature</p>	<p>1. No visual damage 2. Within electric spec (VSWR)</p>
6	Humidity (Steady Condition)	<p>1. Humidity : 85 % RH 1. Temperature : <math>+85 \pm 3^{\circ}\text{C}</math> 2. Time : <math>1000 \pm 24</math> hrs 3. Measure <math>f_c</math> after left for 48 hrs min. at room temperature</p>	<p>1. No visual damage 2. Within electric spec (VSWR)</p>



## 5. Soldering Recommend

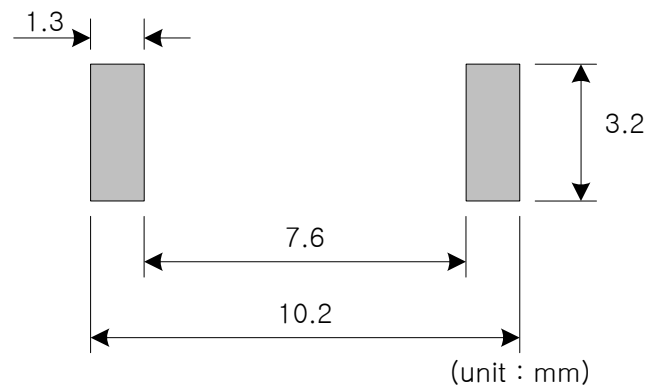
### 5.1 Reflow profile for Pb-free



This product is designed for reflow soldering only. Do not use flow (wave) soldering.

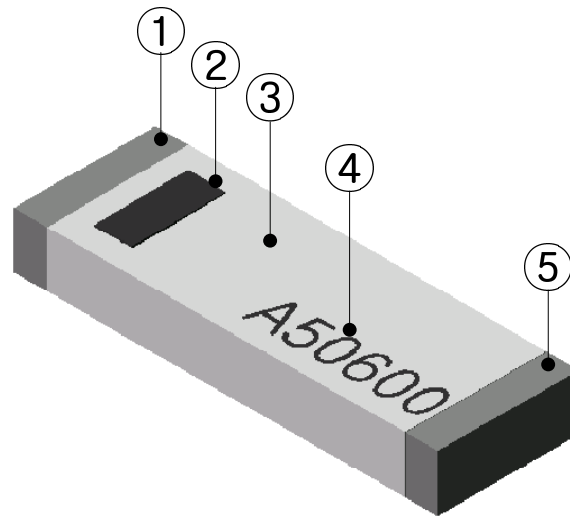
- ① Use non-activated flux (Cl content 0.2% max.)
- ② Follow the recommended soldering conditions to avoid damage.
- ③ Reflow-cycle is max. 3 times.

### 5.2 PCB land pattern



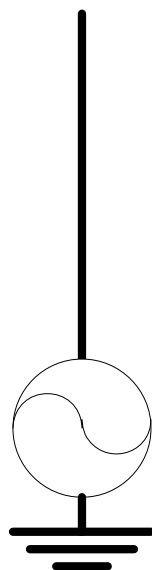
## 6. Structure and Material

### 6.1 Material



No	Part	Function	Material
1	External Electrode	Soldering, Feeding	Ag/Ni/Sn
2	Direction Index	Feeding Index	Ceramic
3	Ceramic Body	–	Ceramic
4	Text	Part No. Index	Ceramic
5	External Electrode	Soldering	Ag/Ni/Sn

### 6.2 Equivalent symbol

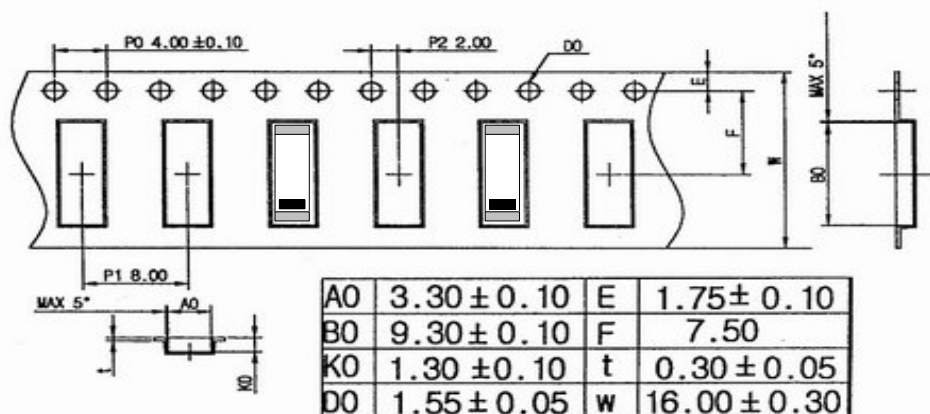


## 7. Cautions

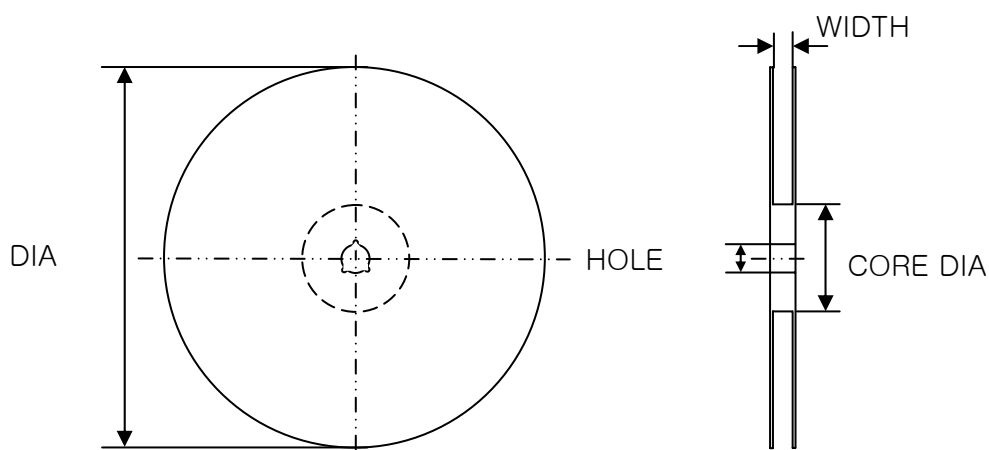
- ① Storage environment must be at ambient temperature of 15~35℃ and ambient humidity of 45~75 % RH. (MSL Level 2)
- ② Chip antenna can experience degradation of termination solder ability when subjected to high temperature of humidity, or if exposed to sulfur or chlorine gases.
- ③ Avoid mechanical shock (ex. falling) to the chip antenna to prevent mechanical cracking inside of the ceramic dielectric due to its own weight.

## 8. Packing Method

### 8.1 Carrier-tape



### 8.2 Reel



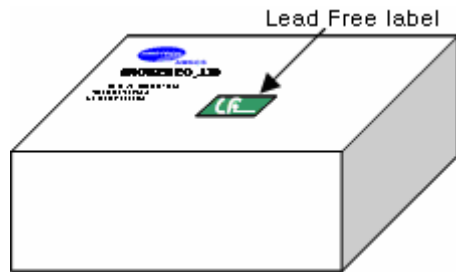
item	DIA	WIDTH	CORE DIA	HOLE
dimension(mm)	180.0 ± 0.3	17.0 ± 0.3	60.0 ± 1	13.0 ± 0.5

### 8.3 Packing box

#### 8.3.1 Small box

Size : 185 (W) x 185 (D) x 68 (H) (mm)

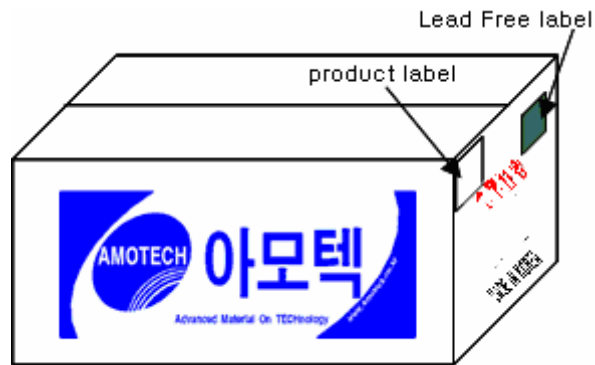
Q'TY : 3 reel (1,000 ea/reel × 3 reel = 3,000 ea)



#### 8.3.2 Middle box

Size : 365 (W) x 200 (D) x 200 (H) (mm)

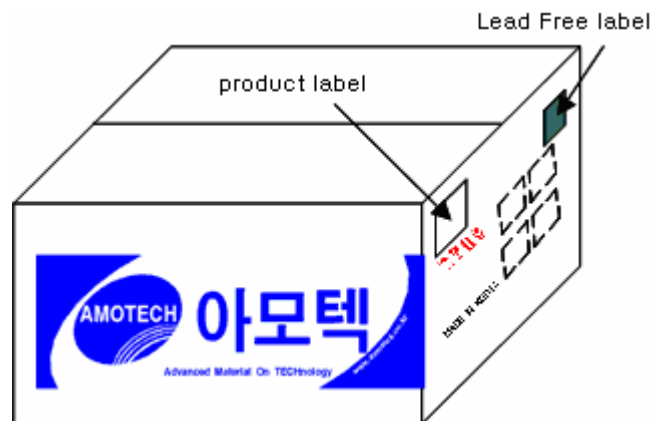
Q'TY : 5 small box(3,000 ea/small box × 5 small box = 15,000 ea)



#### 8.3.3 Large box

Size : 390 (W) x 390 (D) x 280 (H) (mm)

Q'TY : 14 small box(3,000 ea/ small box × 14 small box = 42,000 ea)



## 9. Manufacture and Place

### 9.1 Manufacture

Amotech Co., Ltd

### 9.2 Place

5B 1L, Namdong Industrial Complex, 617 Namchondong, Namdonggu,  
Incheon, Korea

**Test Report No. F690501/LF-CTSGP06-24480**

Date: September 25, 2006

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To: **AMOTECH CO., LTD.**  
5BL-1L, 617  
Namchon-dong  
Namdong-gu  
INCHEON 405-100  
Korea

The following merchandise was submitted and identified by the client as :

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**Commodity** : Multilayer Chip Antenna  
**SGS File No.** : GP06-24480  
**Received Date** : September 18, 2006  
**Test Performing Date** : September 19, 2006  
**Test Performed** : SGS Testing Korea tested the sample(s) selected by applicant with following results  
**Test Results** : For further details, please refer to following page(s)

Jade Jang  
Monet Jeong  
Jully Oh  
Jerry Jung  
/Testing Person

**SGS Testing Korea Co. Ltd.****Jeff Jang / Chemical Lab Mgr**



## Test Report No. F690501/LF-CTSGP06-24480

Date: September 25, 2006

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Sample No. : GP06-24480.001  
Sample Description : Multilayer Chip Antenna  
Style/Item No. : Multilayer Chip Antenna

### Heavy Metals

Test Items	Unit	Test Method	MDL	Results
Cadmium (Cd)	mg/kg	US EPA 3050B(1996), US EPA 6010B(1996), ICP	0.5	N.D.
Lead (Pb)	mg/kg	US EPA 3050B(1996), US EPA 6010B(1996), ICP	5	N.D.
Mercury (Hg)	mg/kg	US EPA 3052(1996), US EPA 6010B(1996), ICP	2	N.D.
Hexavalent Chromium (Cr VI)	mg/kg	US EPA 3060A(1996), US EPA 7196A(1992), UV	1	N.D.

### Flame Retardants-PBBs/PBDEs

Test Items	Unit	Test Method	MDL	Results
Monobromobiphenyl	mg/kg	US EPA 3540C, GC/MS	5	N.D.
Dibromobiphenyl	mg/kg	US EPA 3540C, GC/MS	5	N.D.
Tribromobiphenyl	mg/kg	US EPA 3540C, GC/MS	5	N.D.
Tetrabromobiphenyl	mg/kg	US EPA 3540C, GC/MS	5	N.D.
Pentabromobiphenyl	mg/kg	US EPA 3540C, GC/MS	5	N.D.
Hexabromobiphenyl	mg/kg	US EPA 3540C, GC/MS	5	N.D.
Heptabromobiphenyl	mg/kg	US EPA 3540C, GC/MS	5	N.D.
Octabromobiphenyl	mg/kg	US EPA 3540C, GC/MS	5	N.D.
Nonabromobiphenyl	mg/kg	US EPA 3540C, GC/MS	5	N.D.
Decabromobiphenyl	mg/kg	US EPA 3540C, GC/MS	5	N.D.
Monobromodiphenyl ether	mg/kg	US EPA 3540C, GC/MS	5	N.D.
Dibromodiphenyl ether	mg/kg	US EPA 3540C, GC/MS	5	N.D.
Tribromodiphenyl ether	mg/kg	US EPA 3540C, GC/MS	5	N.D.
Tetrabromodiphenyl ether	mg/kg	US EPA 3540C, GC/MS	5	N.D.
Pentabromodiphenyl ether	mg/kg	US EPA 3540C, GC/MS	5	N.D.
Hexabromodiphenyl ether	mg/kg	US EPA 3540C, GC/MS	5	N.D.
Heptabromodiphenyl ether	mg/kg	US EPA 3540C, GC/MS	5	N.D.
Octabromodiphenyl ether	mg/kg	US EPA 3540C, GC/MS	5	N.D.
Nonabromodiphenyl ether	mg/kg	US EPA 3540C, GC/MS	5	N.D.
Decabromodiphenyl ether	mg/kg	US EPA 3540C, GC/MS	5	N.D.

NOTE: (1) N.D. = Not detected.(<MDL)  
(2) ppm = mg/kg  
(3) MDL = Method Detection Limit  
(4) - = No regulation  
(5) \*\* = Qualitative analysis (No Unit)  
(6) Negative = Undetectable / Positive = Detectable

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**Picture of Sample as Received:**



\*\*\* End \*\*\*

- NOTE:
- (1) N.D. = Not detected.( $<$ MDL)
  - (2) ppm = mg/kg
  - (3) MDL = Method Detection Limit
  - (4) - = No regulation
  - (5) \*\* = Qualitative analysis (No Unit)
  - (6) Negative = Undetectable / Positive = Detectable